TOSHIBA PHOTOCOUPLER GaAs IRED & PHOTO-TRIAC

TLP3041(S),TLP3042(S),TLP3043(S)

OFFICE MACHINE HOUSEHOLD USE EQUIPMENT TRIAC DRIVER SOLID STATE RELAY

The TOSHIBA TLP3041 (S), TLP3042 (S), TLP3043 (S) consist of a zero voltage crossing turn-on photo-triac optically coupled to a gallium arsenide infrared emitting diode in a six lead plastic DIP package.

•	Peak Off-State Voltage	: 400 V (min)

- Trigger LED Current : 15 mA (max) (TLP3041(S)) ۰
 - 5 mA (max) (TLP3043(S))

: 100 mA (max)

: SS EN60065

- **On-State Current**
 - Isolation Voltage : 5000 Vrms (min) : UL1577, File No. E67349
- UL Recognized
- **SEMKO** Approved
- BSI Approved
- 10 mA (max) (TLP3042(S))



- : BS EN60065, File No.8385 BS EN60950, File No.8386

SS EN60950, File No.9841109

Option (D4) type VDE approved: DIN EN60747-5-2

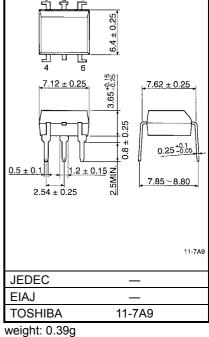
Approved No. 40009302

Maximum operating insulation voltage: 890VPK Highest permissible over voltage: 8000VPK

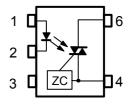
(Note):When a EN60747-5-2 approved type is needed, please designate the "Option (D4)"

Construction mechanical rating

		0	
Creepage Distance7.0 mm (Min)8.0 mm (Min)Clearance7.0 mm (Min)8.0 mm (Min)		7.62 mm pich	10.16 mm pich
Clearance 7.0 mm (Min) 8.0 mm (Min)		Standard Type	TLPxxxxF Type
	Clearance	7.0 mm (Min)	8.0 mm (Min)
	Insulation Thickness	0.5 mm (Min)	0.5 mm (iviin)



Pin Configuration (top view)



1: Anode 2: Cathode 3: N.C. 4:Terminal 1 6:Terminal 2

ZC:Zero-cross Circuit

Unit: mm

MAXIMUM RATINGS (Ta = 25°C)

	CHARACTERIST	IC	SYMBOL	RATING	UNIT	
LED	Forward Current		١ _F	50	mA	
	Forward Current Derating (Ta ≥ 53°C)		ΔI _F / °C	-0.7	mA / °C	
	Peak Forward Current (100, //s pulse, 100pps)		I _{FP}	1	А	
	Power Dissipation		PD	100	mW	
	Power Dissipation Dera (Ta ≥ 25°C)	ating	ΔP _D / °C	-1.0	mW / °C	
	Reverse Voltage		V _R	5	V	
	Junction Temperature		Tj	125	°C	
	Off-State Output Termi	nal Voltage	V _{DRM}	400	V	
	On-Stage RMS	Ta = 25°C		100	mA	
	Current	Ta = 70°C	I _{T(RMS)}	50	IIIA	
с	On-State Current Derating (Ta ≥ 25°C)		ΔI _T / °C	-1.1	mA / °C	
DETECTOR	Peak On-Stage Current (100,4/s pulse, 120pps)		I _{TP}	2	А	
DET	Peak Nonrepetitive Surge Current (P _W = 10ms, DC = 10%)		I _{TSM}	1.2	А	
	Power Dissipation		PD	300	mW	
	Power Dissipation Derating (Ta ≥ 25°C)		ΔP _D / °C	-4.0	mW / °C	
	Junction Temperature		Tj	115	°C	
Stora	age Temperature Range		T _{stg}	-55 ~ 150	°C	
Operating Temperature Range			T _{opr}	-40 ~ 100	°C	
Lead Soldering Temperature (10s)			T _{sol}	260	°C	
Total Package Power Dissipation		Ρ _T	330	mW		
Total Package Power Dissipation Derating (Ta ≥ 25°C)		ΔP _T / °C	-4.4	mW / °C		
	tion Voltage 1 min., R.H. ≤ 60%)	BVS	5000	Vrms		

Note 1: Device considered a two terminal device: Pins 1, 2 and 3 shorted together and pins 4 and 6 shorted together.

RECOMMENDED OPERATING CONDISTIONS

CHARACTERISTIC	SYMBOL	MIN	TYP.	MAX	UNIT
Supply Voltage	V _{AC}	_	_	120	Vac
Forward Current	I _F *	15	20	25	mA
Peak On-Stage Current	I _{TP}	_	_	1	А
Operating Temperature	T _{opr}	-25		85	°C

*: In the case of TLP3042

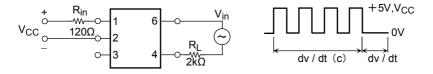
INDIVIDUAL ELECTRICAL CHARACTERISTICS (Ta = 25°C)

	CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
	Forward Voltage	V _F	I _F = 10mA	1.0	1.15	1.3	V
LED	Reverse Current	I _R	V _R = 5V	_	_	10	μA
	Capacitance	CT	V = 0, f = 1MHz	_	10	_	pF
DETECTOR	Peak Off-State Current	I _{DRM}	V _{DRM} = 400V	_	10	100	nA
	Peak On-Stage Voltage	V _{TM}	I _{TM} = 100mA	_	1.7	3.0	V
	Holding Current	Ι _Η	—	_	0.6	_	mA
	Critical Rate of Rise of Off- State Voltage	dv / dt	V _{in} = 120Vrms, Ta = 85°C (Fig.1)	200	500		V / μs
	Critical Rate of Rise of Commutating Voltage	dv / dt(c)	V _{in} = 30Vrms, IT = 15mA (Fig.1)		0.2		V / μs

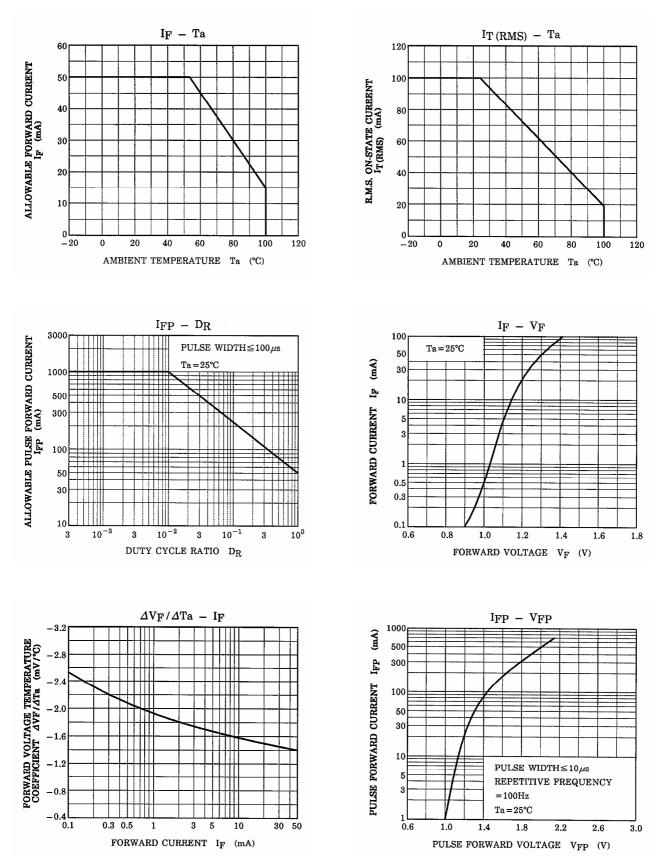
COUPLED ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
	TLP3041(S)		V _T = 3V	_	_	15	mA
Trigger LED Current	TLP3042(S)	I _{FT}			5	10	
	TLP3043(S)				_	5	
Inhibit Voltage		V _{IH}	I _F = Rated I _{FT}		_	40	V
Leakage in Inhibited State		Ін	I _F = Rated I _{FT} V _T = Rated V _{DRM}	_	100	300	μA
Capacitance Input to Output		CS	V _S = 0, f = 1MHz		0.8	_	pF
Isolation Resistance		R _S	V _S = 500V (R.H. ≤ 60%)	5×10 ¹⁰	10 ¹⁴		Ω
Isolation Voltage		BVS	AC, 1 minute	5000	_	_	Vrms
			AC, 1 second (in oil)		10000	_	VIIIIS
			DC, 1 minute (in oil)		10000		Vdc

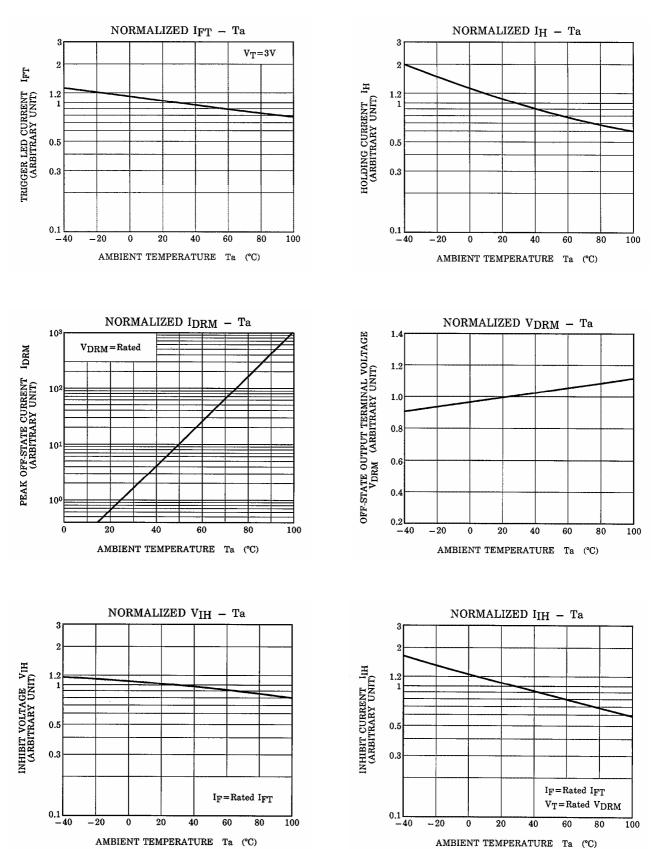
Fig. 1 dv / dt test circuit



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